National Semiconductor

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LM613
Dual Operational Amplifiers, Dual Comparators, and Adjustable Reference

General Description

The LM613 consists of dual op-amps, dual comparators, and a programmable voltage reference in a 16-pin package. The op-amps out-performs most single-supply op-amps by providing higher speed and bandwidth along with low supply current. This device was specifically designed to lower cost and board space requirements in transducer, test, measurement, and data acquisition systems.

Combining a stable voltage reference with wide output swing op-amps makes the LM613 ideal for single supply transducers, signal conditioning and bridge driving where large common-mode-signals are common. The voltage reference consists of a reliable band-gap design that maintains low dynamic output impedance (1Ω typical), excellent initial tolerance (0.6%), and the ability to be programmed from 1.2V to 6.3V via two external resistors. The voltage reference is very stable even when driving large capacitive loads, as are commonly encountered in CMOS data acquisition systems.

As a member of National's Super-Block™ family, the LM613 is a space-saving monolithic alternative to a multi-chip solution, offering a high level of integration without sacrificing performance.

Features

OP AMP
- Low operating current (Op Amp): 300 µA
- Wide supply voltage range: 4V to 36V
- Wide common-mode range: V⁻ to (V⁺ − 1.8V)
- Wide differential input voltage: ±36V
- Available in plastic package rated for Military Temp. Range Operation

REFERENCE
- Adjustable output voltage: 1.2V to 6.3V
- Tight initial tolerance available: ±0.6%
- Wide operating current range: 17 µA to 20 mA
- Tolerant of load capacitance

Applications

- Transducer bridge driver
- Process and mass flow control systems
- Power supply voltage monitor
- Buffered voltage references for A/D's

Connection Diagrams

Top View

DS009226-1

E Package Pinout

DS009226-48
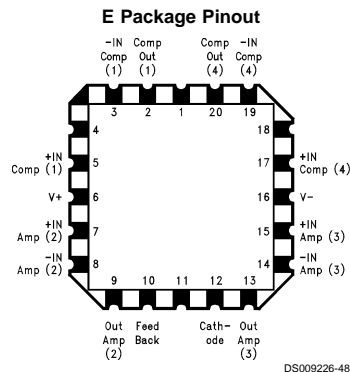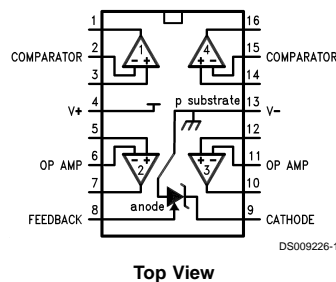
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Ordering Information

Reference Tolerance & V_{OS}	Temperature Range			Package	NSC Drawing
	Military −55˚C ≤ T_A ≤ +125˚C	**Industrial** −40˚C ≤ T_A ≤ +85˚C	**Commercial** 0˚C ≤ T_A ≤ +70˚C		
±0.6% 80 ppm/˚C Max. V_{OS} ≤ 3.5 mV	LM613AMN	LM613AIN	—	16-Pin Molded DIP	N16E
	LM613AMJ/883 (Note 14)	—	—	16-Pin Ceramic DIP	J16A
	LM613AME/883 (Note 14)	—	—	20-Pin LCC	E20A
±2.0% 150 ppm/˚C Max. V_{OS} ≤ 5.0 mV Max.	LM613MN	LM613IN	LM613CN	16-Pin Molded DIP	N16E
	—	LM613IWM		16-Pin Wide Surface Mount	M16B

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Voltage on Any Pin Except V_R
(referred to V$^-$pin)

(Note 2)	36V (Max)
(Note 3)	−0.3V (Min)

Current through Any Input Pin
& V_R Pin   ±20 mA

Differential Input Voltage

Military and Industrial	±36V
Commercial	±32V

Storage Temperature Range   −65˚C ≤ T_J ≤ +150˚C

				LM613AM	LM613M	
			Typical	LM613AI	LM613I	
Symbol	Parameter	Conditions	(Note 7)	Limits	LM613C	Units
				(Note 8)	Limits	
					(Note 8)	

Maximum Junction Temp.(Note 4)   150˚C

Thermal Resistance,
Junction-to-Ambient (Note 5)
  N Package   100˚C/W
  WM Package   150˚C/W

Soldering Information (10 Sec.)
  N Package   260˚C
  WM Package   220˚C

ESD Tolerance (Note 6)   ±1 kV

Operating Temperature Range

LM613AI, LM613BI: −40˚C to +85˚C
LM613AM, LM613M: −55˚C to +125˚C
LM613C: $0˚C \leq T_J \leq +70˚C$

Electrical Characteristics

These specifications apply for $V^- = $ GND $= 0V$, $V^+ = 5V$, $V_{CM} = V_{OUT} = 2.5V$, $I_R = 100$ µA, FEEDBACK pin shorted to GND, unless otherwise specified. Limits in standard typeface are for $T_J = 25˚C$; limits in **boldface type** apply over the **Operating Temperature Range**.

Symbol	Parameter	Conditions	Typical (Note 7)	LM613AM LM613AI Limits (Note 8)	LM613M LM613I LM613C Limits (Note 8)	Units
I_S	Total Supply Current	$R_{LOAD} = \infty$,	450	940	1000	µA (Max)
		$4V \leq V^+ \leq 36V$ (32V for LM613C)	**550**	**1000**	**1070**	µA (Max)
V_S	Supply Voltage Range		2.2	2.8	2.8	V (Min)
			2.9	**3**	**3**	V (Min)
			46	36	32	V (Max)
			43	**36**	**32**	V (Max)
OPERATIONAL AMPLIFIERS						
V_{OS1}	V_{OS} Over Supply	$4V \leq V^+ \leq 36V$	1.5	3.5	5.0	mV (Max)
		($4V \leq V^+ \leq 32V$ for LM613C)	**2.0**	**6.0**	**7.0**	mV (Max)
V_{OS2}	V_{OS} Over V_{CM}	$V_{CM} = 0V$ through $V_{CM} =$	1.0	3.5	5.0	mV (Max)
		$(V^+ - 1.8V)$, $V^+ = 30V$, $V^- = 0V$	**1.5**	**6.0**	**7.0**	mV (Max)
$\dfrac{V_{OS3}}{\Delta T}$	Average V_{OS} Drift	(Note 8)	**15**			µV/˚C (Max)
I_B	Input Bias Current		10	25	35	nA (Max)
			11	**30**	**40**	nA (Max)
I_{OS}	Input Offset Current		0.2	4	4	nA (Max)
			0.3	**5**	**5**	nA (Max)
$\dfrac{I_{OS1}}{\Delta T}$	Average Offset Current		**4**			pA/˚C
R_{IN}	Input Resistance	Differential	1000			MΩ
C_{IN}	Input Capacitance	Common-Mode	6			pF
e_n	Voltage Noise	$f = 100$ Hz, Input Referred	74			nV/$\sqrt{Hz}$
I_n	Current Noise	$f = 100$ Hz, Input Referred	58			fA/$\sqrt{Hz}$
CMRR	Common-Mode	$V^+ = 30V$, $0V \leq V_{CM} \leq (V^+ - 1.8V)$	95	80	75	dB (Min)
	Rejection Ratio	CMRR $= 20$ log $(\Delta V_{CM}/\Delta V_{OS})$	**90**	**75**	**70**	dB (Min)
PSRR	Power Supply	$4V \leq V^+ \leq 30V$, $V_{CM} = V^+/2$,	110	80	75	dB (Min)
	Rejection Ratio	PSRR $= 20$ log $(\Delta V^+/V_{OS})$	**100**	**75**	**70**	dB (Min)
A_V	Open Loop	$R_L = 10$ kΩ to GND, $V^+ = 30V$,	500	100	94	V/mV
	Voltage Gain	$5V \leq V_{OUT} \leq 25V$	**50**	**40**	**40**	(Min)
SR	Slew Rate	$V^+ = 30V$ (Note 9)	0.70	0.55	0.50	V/µs
			0.65	**0.45**	**0.45**	
GBW	Gain Bandwidth	$C_L = 50$ pF	0.8			MHz
			0.5			MHz

Electrical Characteristics (Continued)

These specifications apply for $V^- = $ GND $= 0V$, $V^+ = 5V$, $V_{CM} = V_{OUT} = 2.5V$, $I_R = 100$ µA, FEEDBACK pin shorted to GND, unless otherwise specified. Limits in standard typeface are for $T_J = 25°C$; limits in **boldface type** apply over the **Operating Temperature Range**.

Symbol	Parameter	Conditions	Typical (Note 7)	LM613AM LM613AI Limits (Note 8)	LM613M LM613I LM613C Limits (Note 8)	Units
OPERATIONAL AMPLIFIERS						
V_{O1}	Output Voltage Swing High	$R_L = 10$ kΩ to GND, $V^+ = 36V$ (32V for LM613C)	$V^+ - 1.4$ **$V^+ - 1.6$**	$V^+ - 1.7$ **$V^+ - 1.9$**	$V^+ - 1.8$ **$V^+ - 1.9$**	V (Min) V (Min)
V_{O2}	Output Voltage Swing Low	$R_L = 10$ kΩ to V^+, $V^+ = 36V$ (32V for LM613C)	$V^- + 0.8$ **$V^- + 0.9$**	$V^- + 0.9$ **$V^- + 1.0$**	$V^- + 0.95$ **$V^- + 1.0$**	V (Max) V (Max)
I_{OUT}	Output Source Current	$V_{OUT} = 2.5V$, $V^+_{IN} = 0V$, $V^-_{IN} = -0.3V$	25 **15**	20 **13**	16 **13**	mA (Min) mA (Min)
I_{SINK}	Output Sink Current	$V_{OUT} = 1.6V$, $V^+_{IN} = 0V$, $V^-_{IN} = 0.3V$	17 **9**	14 **8**	13 **8**	mA (Min) mA (Min)
I_{SHORT}	Short Circuit Current	$V_{OUT} = 0V$, $V^+_{IN} = 3V$, $V^-_{IN} = 2V$	30 **40**	50 **60**	50 **60**	mA (Max) mA (Max)
		$V_{OUT} = 5V$, $V^+_{IN} = 2V$, $V^-_{IN} = 3V$	30 **32**	60 **80**	70 **90**	mA (Max) mA (Max)
COMPARATORS						
V_{OS}	Offset Voltage	$4V \leq V^+ \leq 36V$ (32V for LM613C), $R_L = 15$ kΩ	1.0 **2.0**	3.0 **6.0**	5.0 **7.0**	mV (Max) mV (Max)
$\dfrac{V_{OS}}{V_{CM}}$	Offset Voltage over V_{CM}	$0V \leq V_{CM} \leq 36V$ $V^+ = 36V$, (32V for LM613C)	1.0 **1.5**	3.0 **6.0**	5.0 **7.0**	mV (Max) mV (Max)
$\dfrac{V_{OS}}{\Delta T}$	Average Offset Voltage Drift		**15**			µV/°C (Max)
I_B	Input Bias Current		5 **8**	25 **30**	35 **40**	nA (Max) nA (Max)
I_{OS}	Input Offset Current		0.2 **0.3**	4 **5**	4 **5**	nA (Max) nA (Max)
A_V	Voltage Gain	$R_L = 10$ kΩ to 36V (32V for LM613C) $2V \leq V_{OUT} \leq 27V$	500 **100**			V/mV V/mV
t_r	Large Signal Response Time	$V^+_{IN} = 1.4V$, $V^-_{IN} = $ TTL Swing, $R_L = 5.1$ kΩ	1.5 **2.0**			µs µs
I_{SINK}	Output Sink Current	$V^+_{IN} = 0V$, $V^-_{IN} = 1V$, $V_{OUT} = 1.5V$	20 **13**	10 **8**	10 **8**	mA (Min) mA (Min)
		$V_{OUT} = 0.4V$	2.8 **2.4**	1.0 **0.5**	0.8 **0.5**	mA (Min) mA (Min)
I_{LEAK}	Output Leakage Current	$V^+_{IN} = 1V$, $V^-_{IN} = 0V$, $V_{OUT} = 36V$ (32V for LM613C)	0.1 **0.2**	10	10	µA (Max) µA (Max)
VOLTAGE REFERENCE						
V_R	Voltage Reference	(Note 10)	1.244	1.2365 1.2515 (±0.6%)	1.2191 1.2689 (±2%)	V (Min) V (Max)
$\dfrac{\Delta V_R}{\Delta T}$	Average Temp. Drift	(Note 11)	**10**	80	150	ppm/°C (Max)

Electrical Characteristics (Continued)

These specifications apply for $V^- =$ GND = 0V, $V^+ = 5V$, $V_{CM} = V_{OUT} = 2.5V$, $I_R = 100$ µA, FEEDBACK pin shorted to GND, unless otherwise specified. Limits in standard typeface are for $T_J = 25°C$; limits in **boldface type** apply over the **Operating Temperature Range**.

Symbol	Parameter	Conditions	Typical (Note 7)	LM613AM LM613AI Limits (Note 8)	LM613M LM613I LM613C Limits (Note 8)	Units
VOLTAGE REFERENCE						
$\dfrac{\Delta V_R}{\Delta T_J}$	Hysteresis	(Note 12)	**3.2**			µV/°C
$\dfrac{\Delta V_R}{\Delta I_R}$	V_R Change with Current	$V_{R(100\ µA)} - V_{R(17\ µA)}$	0.05	1	1	mV (Max)
			0.1	**1.1**	**1.1**	mV (Max)
		$V_{R(10\ mA)} - V_{R(100\ µA)}$ (Note 13)	1.5	5	5	mV (Max)
			2.0	**5.5**	**5.5**	mV (Max)
R	Resistance	$\Delta V_{R(10 \to 0.1\ mA)}/9.9$ mA	**0.2**	**0.56**	**0.56**	Ω (Max)
		$\Delta V_{R(100 \to 17\ µA)}/83$ µA	**0.6**	**13**	**13**	Ω (Max)
$\dfrac{V_R}{\Delta V_{RO}}$	V_R Change with High V_{RO}	$V_{R(Vro\ =\ Vr)} - V_{R(Vro\ =\ 6.3V)}$ (5.06V between Anode and FEEDBACK)	2.5	7	7	mV (Max)
			2.8	**10**	**10**	mV (Max)
$\dfrac{V_R}{\Delta V^+}$	V_R Change with V_{ANODE} Change	$V_{R(V+\ =\ 5V)} - V_{R(V+\ =\ 36V)}$ ($V^+ = 32V$ for LM613C)	0.1	1.2	1.2	mV (Max)
			0.1	**1.3**	**1.3**	mV (Max)
		$V_{R(V+\ =\ 5V)} - V_{R(V+\ =\ 3V)}$	0.01	1	1	mV (Max)
			0.01	**1.5**	**1.5**	mV (Max)
I_{FB}	FEEDBACK Bias Current	$V_{ANODE} \leq V_{FB} \leq 5.06V$	22	35	50	nA (Max)
			29	**40**	**55**	nA (Max)
e_n	V_R Noise	10 Hz to 10 kHz, $V_{RO} = V_R$	30			µV$_{RMS}$

Note 1: Absolute maximum ratings indicate limits beyond which damage to the component may occur. Electrical specifications do not apply when operating the device beyond its rated operating conditions.

Note 2: Input voltage above V^+ is allowed. As long as one input pin voltage remains inside the common-mode range, the comparator will deliver the correct output.

Note 3: More accurately, it is excessive current flow, with resulting excess heating, that limits the voltages on all pins. When any pin is pulled a diode drop below V^-, a parasitic NPN transistor turns ON. No latch-up will occur as long as the current through that pin remains below the Maximum Rating. Operation is undefined and unpredictable when any parasitic diode or transistor is conducting.

Note 4: Simultaneous short-circuit of multiple comparators while using high supply voltages may force junction temperature above maximum, and thus should not be continuous.

Note 5: Junction temperature may be calculated using $T_J = T_A + P_D\ \theta_{JA}$. The given thermal resistance is worst-case for packages in sockets in still air. For packages soldered to copper-clad board with dissipation from one comparator or reference output transistor, nominal θ_{JA} is 90°C/W for the N package, and 135°C/W for the WM package.

Note 6: Human body model, 100 pF discharged through a 1.5 kΩ resistor.

Note 7: Typical values in standard typeface are for $T_J = 25°C$; values in **bold face type** apply for the full operating temperature range. These values represent the most likely parametric norm.

Note 8: All limits are guaranteed at room temperature (standard type face) or at operating temperature extremes **(bold type face)**.

Note 9: Slew rate is measured with the op amp in a voltage follower configuration. For rising slew rate, the input voltage is driven from 5V to 25V, and the output voltage transition is sampled at 10V and @ 20V. For falling slew rate, the input voltage is driven from 25V to 5V, and the output voltage transition is sampled at 20V and 10V.

Note 10: V_R is the Cathode-to-feedback voltage, nominally 1.244V.

Note 11: Average reference drift is calculated from the measurement of the reference voltage at 25°C and at the temperature extremes. The drift, in ppm/°C, is $10^6 \cdot \Delta V_R/(V_{R[25°C]} \cdot \Delta T_J)$, where ΔV_R is the lowest value subtracted from the highest, $V_{R[25°C]}$ is the value at 25°C, and ΔT_J is the temperature range. This parameter is guaranteed by design and sample testing.

Note 12: Hysteresis is the change in V_R caused by a change in T_J, after the reference has been "dehysterized". To dehysterize the reference; that is minimize the hysteresis to the typical value, its junction temperature should be cycled in the following pattern, spiraling in toward 25°C: 25°C, 85°C, −40°C, 70°C, 0°C, 25°C.

Note 13: Low contact resistance is required for accurate measurement.
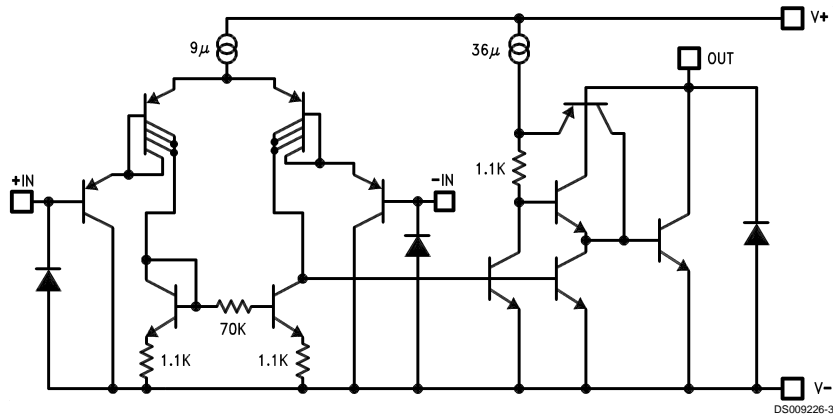
Note 14: A military RETS 613AMX electrical test specification is available on request. The Military screened parts can also be procured as a Standard Military Drawing.
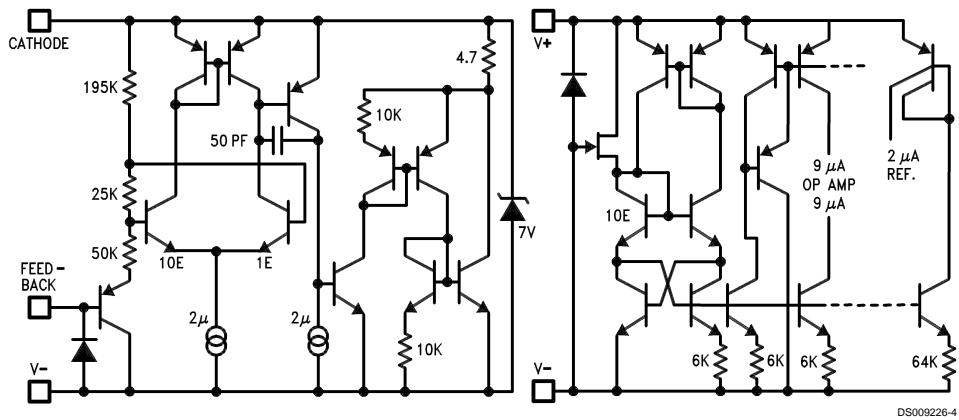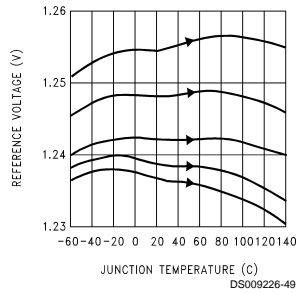
Simplified Schematic Diagrams

Op Amp
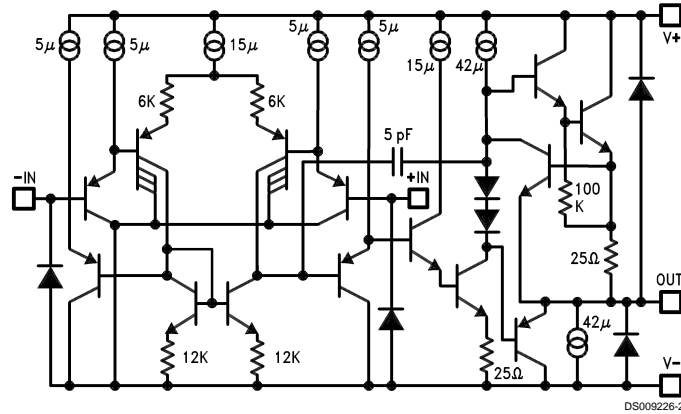
DS009226-2

Comparator
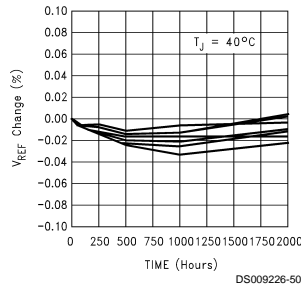

DS009226-3

Reference/Bias

DS009226-4

Typical Performance Characteristics (Reference) T_J = 25°C, FEEDBACK pin shorted to
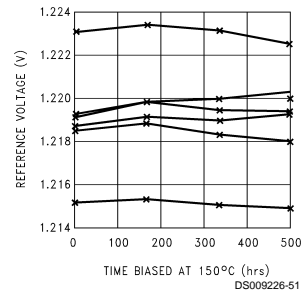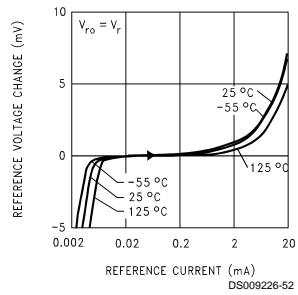V^- = 0V, unless otherwise noted

Reference Voltage vs Temp.

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Reference Voltage Drift

DS009226-50

Accelerated Reference Voltage Drift vs Time

DS009226-51

### Reference Voltage vs Current and Temperature

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Reference Voltage vs Current and Temperature

DS009226-53

Reference Voltage vs Reference Current

DS009226-54

Reference Voltage vs Reference Current

DS009226-55

Reference AC Stability Range

DS009226-56

FEEDBACK Current vs FEEDBACK-to-Anode Voltage

DS009226-57
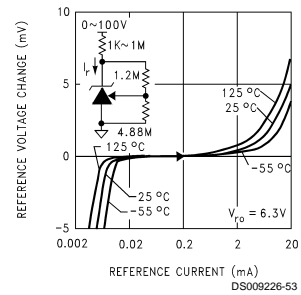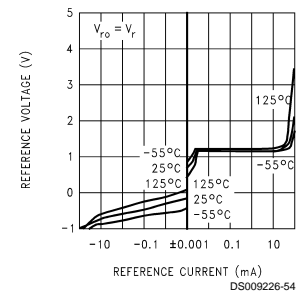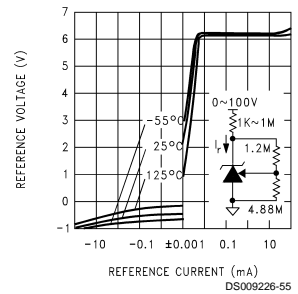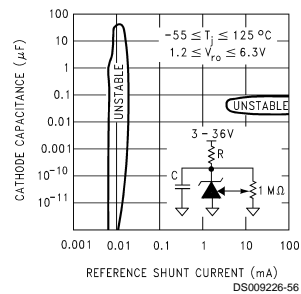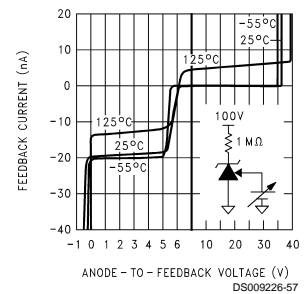
Typical Performance Characteristics (Reference) T_J = 25°C, FEEDBACK pin shorted to V^- = 0V, unless otherwise noted (Continued)

FEEDBACK Current vs FEEDBACK-to-Anode Voltage

DS009226-58
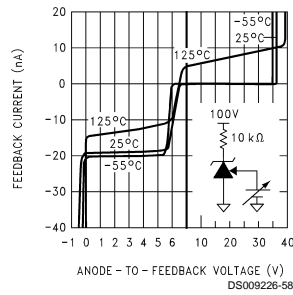
Reference Noise Voltage vs Frequency

DS009226-59
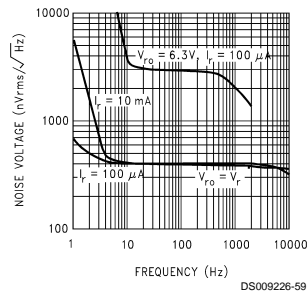
Reference Small-Signal Resistance vs Frequency

DS009226-60
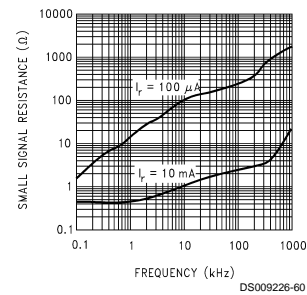
Reference Power-Up Time

DS009226-61
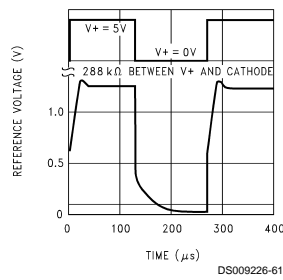
Reference Voltage with FEEDBACK Voltage Step

DS009226-62
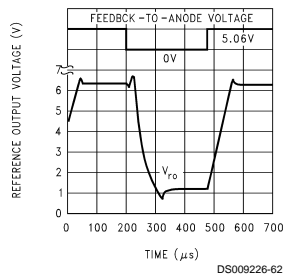
Reference Voltage with 100 ∼ 12 µA Current Step

DS009226-63
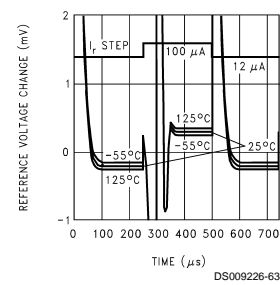
Reference Step Response for 100 µA ∼ 10 mA Current Step

DS009226-64
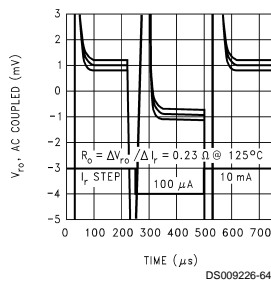
Reference Voltage Change with Supply Voltage Step

DS009226-65
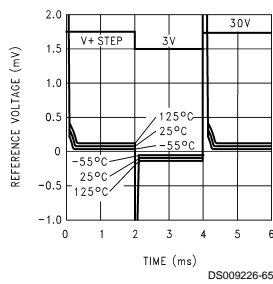
Reference Change vs Common-Mode Voltage
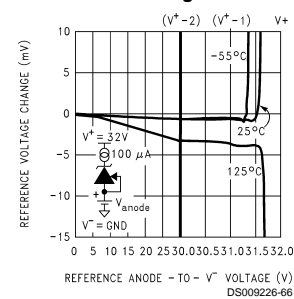
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Typical Performance Characteristics (Op Amps) $V^+ = 5V$, $V^- = GND = 0V$, $V_{CM} = V^+/2$, $V_{OUT} = V^+/2$, $T_J = 25°C$, unless otherwise noted

Input Common-Mode Voltage Range vs Temperature

OUTPUT GOES LOW

NORMAL OPERATING RANGE

OUTPUT GOES LOW

COMMON-MODE VOLTAGE (V)

JUNCTION TEMPERATURE (C)

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V_{OS} vs Junction Temperature

OFFSET VOLTAGE (mV)

JUNCTION TEMPERATURE (C)

DS009226-68

Input Bias Current vs Common-Mode Voltage

INPUT CURRENT (nA)

$V^+ = 5V$

INPUT VOLTAGE (V)

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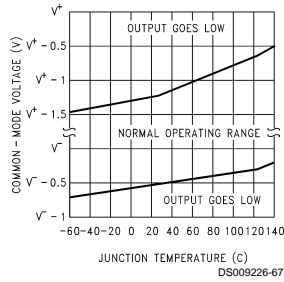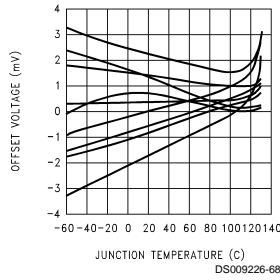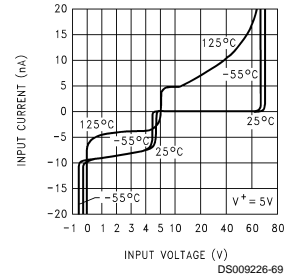
Large-Signal Step Response

$V^+ = 15V$
$V^- = -15V$
FOLLOWER

OUTPUT VOLTAGE (V)

125°C
25°C
-55°C

V_{IN}

TIME (μs)

DS009226-70
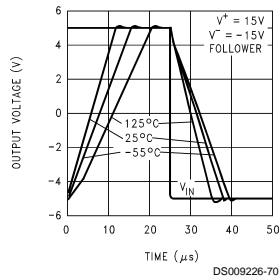
Output Voltage Swing vs Temp. and Current

OUTPUT VOLTAGE (V)

10 mA LOAD   1 μA LOAD
50 μA LOAD

JUNCTION TEMPERATURE (C)

DS009226-71
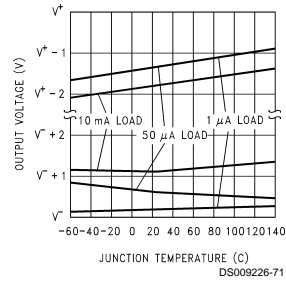
Output Source Current vs Output Voltage and Temp.

$2.8 \leq V^+ \leq 36V$
NEGATIVE INPUT = V^-
$V_{+IN} = V^- + 1V$

125 °C
25 °C
-55 °C

OUTPUT CURRENT (mA)

SUPPLY REFERENCED V_{OUT} (V)

DS009226-72
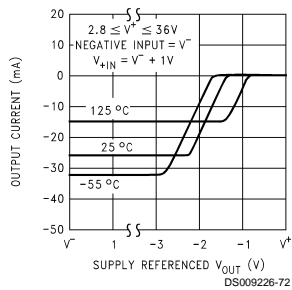
Output Sink Current vs Output Voltage

$V^+ = 30V$

125°C
25°C
-55°C

OUTPUT CURRENT (mA)

OUTPUT VOLTAGE (V)

DS009226-73
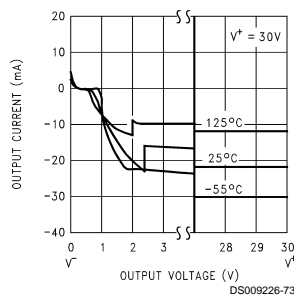
Output Swing, Large Signal
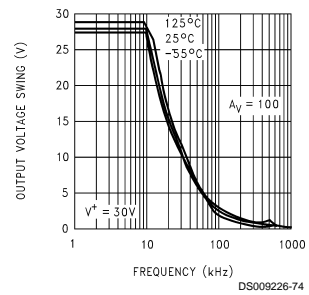
125°C
25°C
-55°C

$A_V = 100$

$V^+ = 30V$

OUTPUT VOLTAGE SWING (V)

FREQUENCY (kHz)

DS009226-74

Typical Performance Characteristics (Op Amps) V^+ = 5V, V^- = GND = 0V, V_{CM} = V^+/2,

V_{OUT} = V^+/2, T_J = 25°C, unless otherwise noted (Continued)

Output Impedance vs Frequency and Gain

DS009226-75
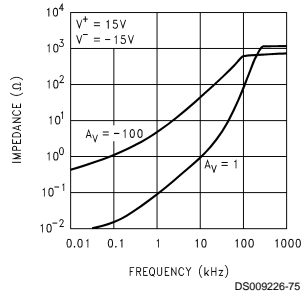
Small Signal Pulse Response vs Temp.

DS009226-76
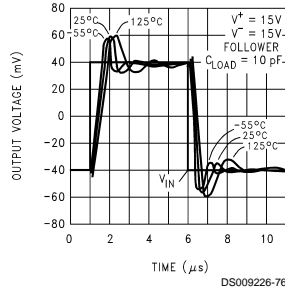
Small-Signal Pulse Response vs Load

DS009226-77
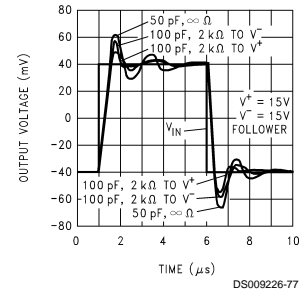
Op Amp Voltage Noise vs Frequency

DS009226-78
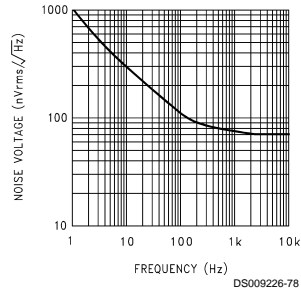
Op Amp Current Noise vs Frequency

DS009226-79
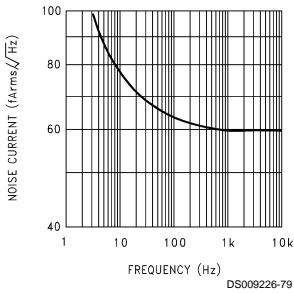
Small-Signal Voltage Gain vs Frequency and Temperature

DS009226-80
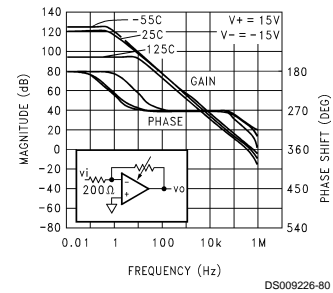
Small-Signal Voltage Gain vs Frequency and Load

DS009226-81
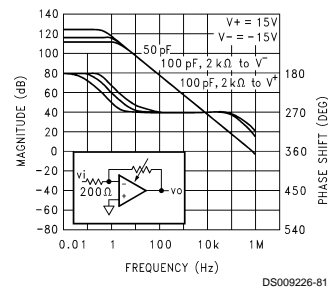
Follower Small-Signal Frequency Response
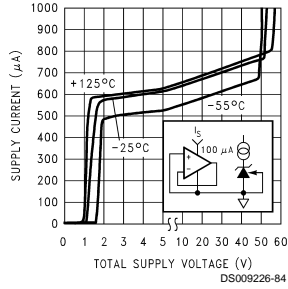

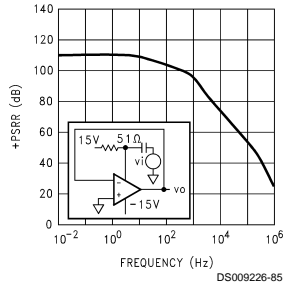DS009226-82
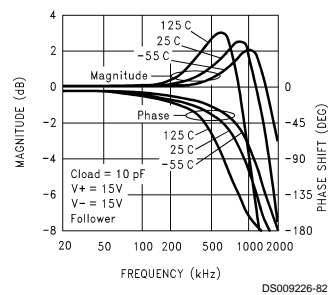
Common-Mode Input Voltage Rejection Ratio
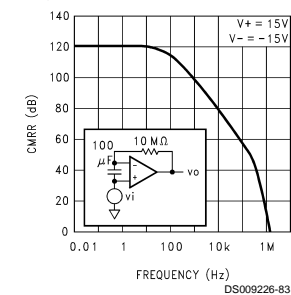
DS009226-83

Typical Performance Characteristics (Op Amps) $V^+ = 5V$, $V^- = GND = 0V$, $V_{CM} = V^+/2$, $V_{OUT} = V^+/2$, $T_J = 25°C$, unless otherwise noted (Continued)

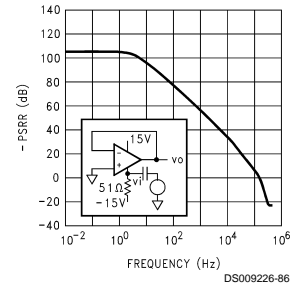**Power Supply Current
vs Power Supply Voltage**

DS009226-84
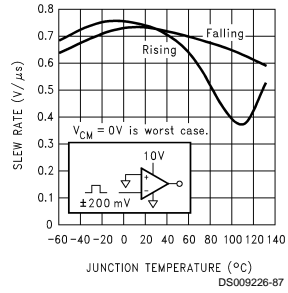
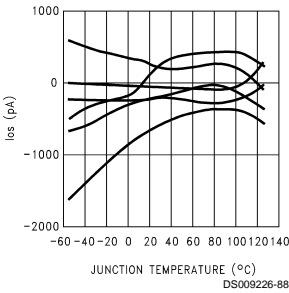**Positive Power Supply
Voltage Rejection Ratio**

DS009226-85

**Negative Power Supply
Voltage Rejection Ratio**

DS009226-86

Slew Rate vs Temperature

DS009226-87

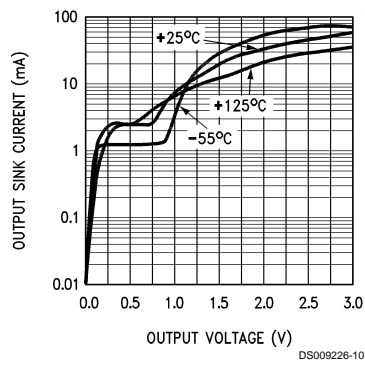**Input Offset Current vs
Junction Temperature**

DS009226-88
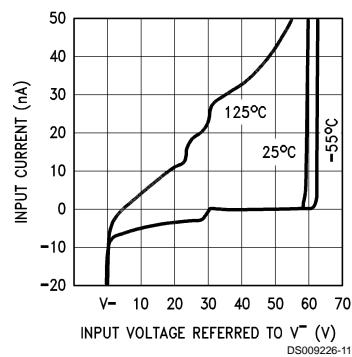
**Input Bias Current vs
Junction Temperature**

DS009226-89
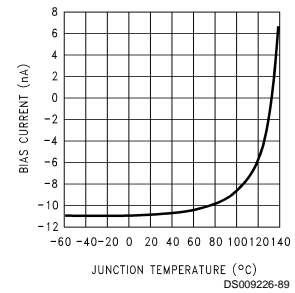
Typical Performance Characteristics (Comparators)

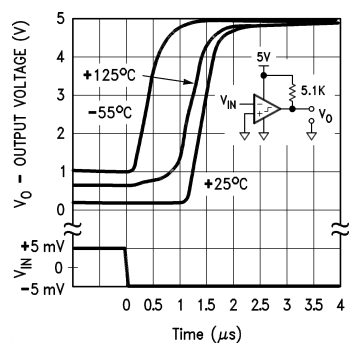**Output Sink Current**

DS009226-10

**Input Bias Current vs
Common-Mode Voltage**

DS009226-11

Typical Performance Characteristics (Comparators) (Continued)

**Comparator
Response Times — Inverting
Input, Positive Transition**

DS009226-12

**Comparator
Response Times — Inverting
Input, Negative Transition**

DS009226-13

**Comparator
Response Times — Non-Inverting
Input, Positive Transition**

DS009226-14

**Comparator
Response Times — Non-Inverting
Input, Negative Transition**

DS009226-15

**Comparator
Response Times — Inverting
Input, Positive Transition**

DS009226-16

**Comparator
Response Times — Inverting
Input, Negative Transition**
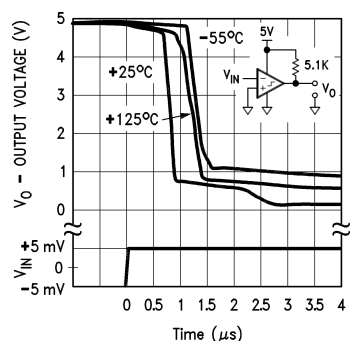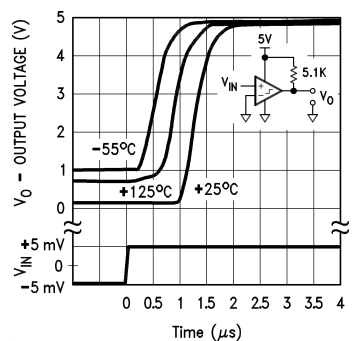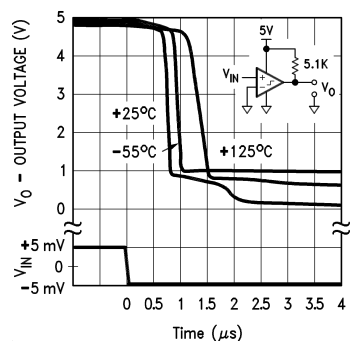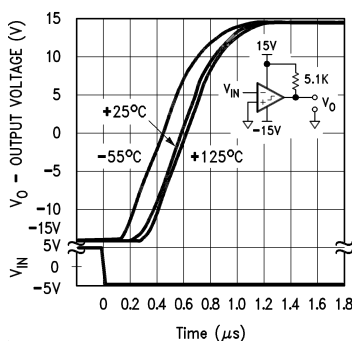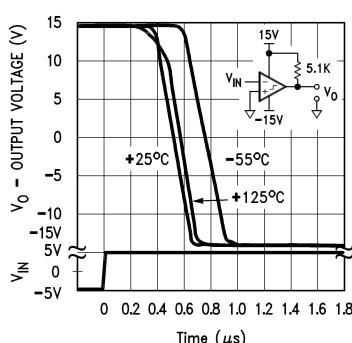

DS009226-17

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Typical Performance Characteristics (Comparators) (Continued)

**Comparator
Response Times — Non-Inverting
Input, Positive Transition**

DS009226-18

**Comparator
Response Times — Non-Inverting
Input, Negative Transition**

DS009226-19
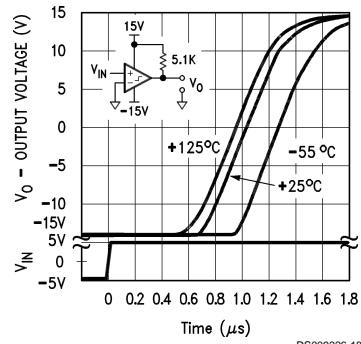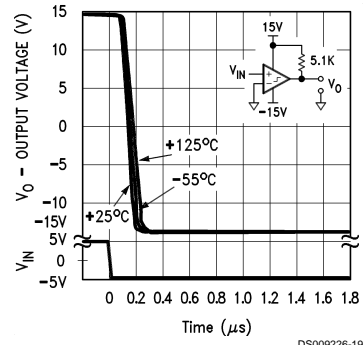
Typical Performance Distributions

**Average V_{OS} Drift
Military Temperature Range**

DS009226-20

**Average V_{OS} Drift
Industrial Temperature Range**

DS009226-21

**Average V_{OS} Drift
Commercial Temperature Range**

DS009226-22
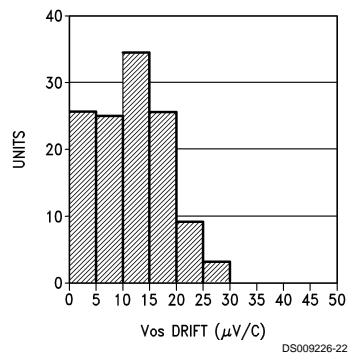
**Average I_{OS} Drift
Military Temperature Range**

DS009226-23

Typical Performance Distributions (Continued)

Average I_{OS} Drift
Industrial Temperature Range

los DRIFT (pA/C)

DS009226-24
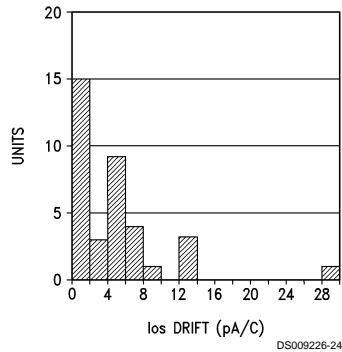
Op Amp Voltage
Noise Distribution

VOLTAGE NOISE ($nV_{RMS}/\sqrt{Hz}$)

DS009226-27
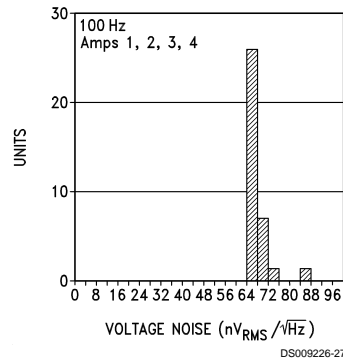
Average I_{OS} Drift
Commercial Temperature Range

los DRIFT (pA/C)

DS009226-25
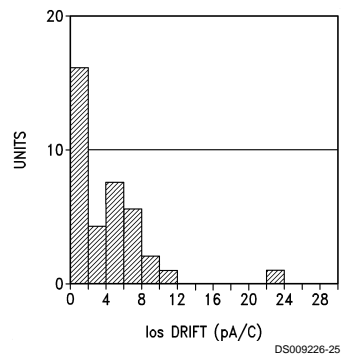
Op Amp Current
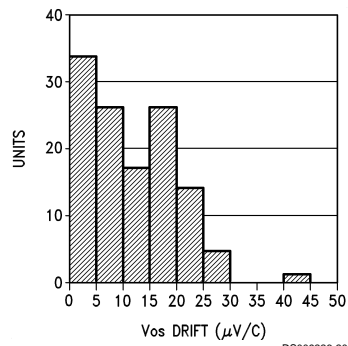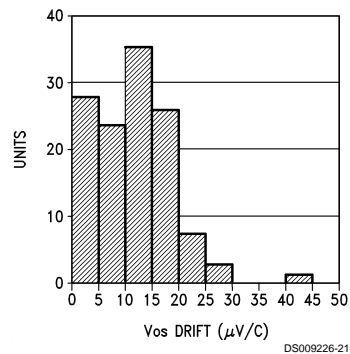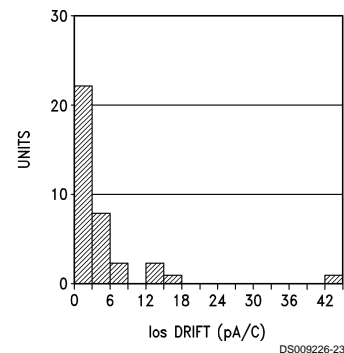**Noise Distribution**

CURRENT NOISE ($fA_{RMS}/\sqrt{Hz}$)

DS009226-28
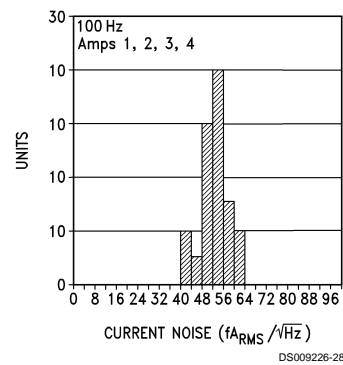
Voltage Reference Broad-Band
Noise Distribution

VOLTAGE NOISE (μV_{RMS})

DS009226-26
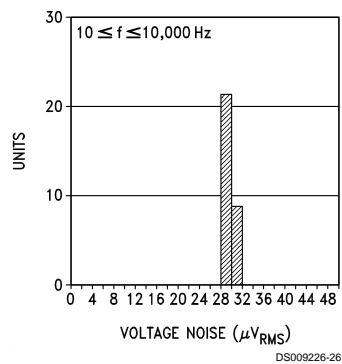
Application Information

VOLTAGE REFERENCE

Reference Biasing

The voltage reference is of a shunt regulator topology that models as a simple zener diode. With current I_r flowing in the "forward" direction there is the familiar diode transfer function. I_r flowing in the reverse direction forces the reference voltage to be developed from cathode to anode. The cathode may swing from a diode drop below V^- to the reference voltage or to the avalanche voltage of the parallel protection diode, nominally 7V. A 6.3V reference with $V^+ = 3V$ is allowed.

Application Information (Continued)
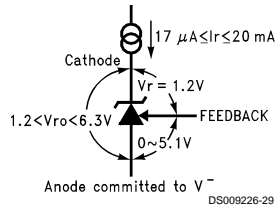
FIGURE 1. Voltage Associated with Reference (current source I_r is external)

The reference equivalent circuit reveals how V_r is held at the constant 1.2V by feedback, and how the FEEDBACK pin passes little current.

To generate the required reverse current, typically a resistor is connected from a supply voltage higher than the reference voltage. Varying that voltage, and so varying I_r, has small effect with the equivalent series resistance of less than an ohm at the higher currents. Alternatively, an active current source, such as the LM134 series, may generate I_r.

FIGURE 2. Reference Equivalent Circuit

FIGURE 3. 1.2V Reference

Capacitors in parallel with the reference are allowed. See the Reference AC Stability Range typical curve for capacitance values — from 20 µA to 3 mA any capacitor value is stable. With the reference's wide stability range with resistive and capacitive loads, a wide range of RC filter values will perform noise filtering.

Adjustable Reference

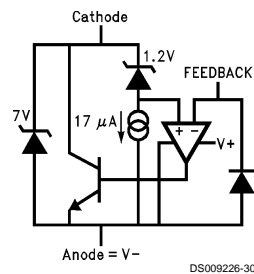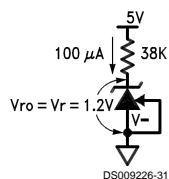The FEEDBACK pin allows the reference output voltage, V_{ro}, to vary from 1.24V to 6.3V. The reference attempts to hold V_r at 1.24V. If V_r is above 1.24V, the reference will conduct current from Cathode to Anode; FEEDBACK current always remains low. If FEEDBACK is connected to Anode, then $V_{ro} = V_r = 1.24$V. For higher voltages FEEDBACK is held at a constant voltage above Anode — say 3.76V for V_{ro} = 5V. Connecting a resistor across the constant V_r generates a current I=R1/V_r flowing from Cathode into FEEDBACK

node. A Thevenin equivalent 3.76V is generated from FEED-BACK to Anode with R2=3.76/I. Keep I greater than one thousand times larger than FEEDBACK bias current for <0.1% error — I≥32 µA for the military grade over the military temperature range (I≥5.5 µA for a 1% untrimmed error for a commercial part).
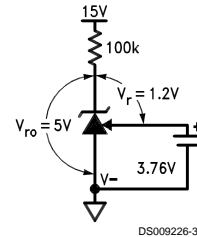
FIGURE 4. Thevenin Equivalent of Reference with 5V Output
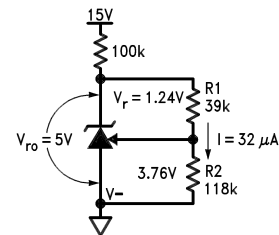
R1 = Vr/I = 1.24/32µ = 39k
R2 = R1 {(Vro/Vr) − 1} = 39k {(5/1.24) − 1)} = 118k

FIGURE 5. Resistors R1 and R2 Program Reference Output Voltage to be 5V

Understanding that V_r is fixed and that voltage sources, resistors, and capacitors may be tied to the FEEDBACK pin, a range of V_r temperature coefficients may be synthesized.
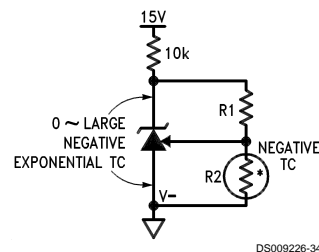
FIGURE 6. Output Voltage has Negative Temperature Coefficient (TC) if R2 has Negative TC

Application Information (Continued)

FIGURE 7. Output Voltage has Positive TC
if R1 has Negative TC

FIGURE 8. Diode in Series with R1 Causes Voltage
Across R1 and R2 to be Proportional to Absolute
Temperature (PTAT)

Connecting a resistor across Cathode-to-FEEDBACK creates a 0 TC current source, but a range of TCs may be synthesized.
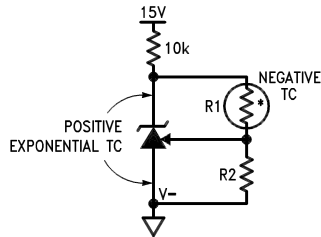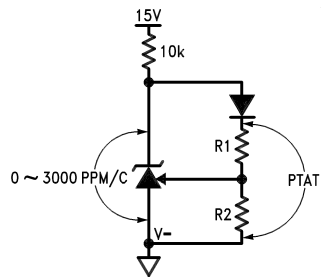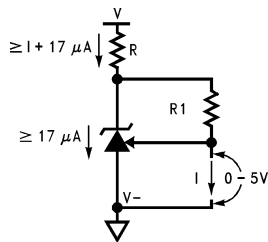

$I = Vr/R1 = 1.24/R1$

FIGURE 9. Current Source is Programmed by R1
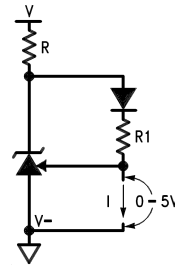
FIGURE 10. Proportional-to-Absolute-Temperature
Current Source
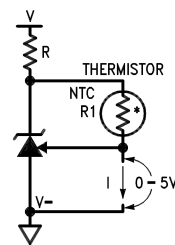
FIGURE 11. Negative-TC Current Source

Reference Hysteresis

The reference voltage depends, slightly, on the thermal history of the die. Competitive micro-power products vary — always check the data sheet for any given device. Do not assume that no specification means no hysteresis.

OPERATIONAL AMPLIFIERS AND COMPARATORS

Any amp, comparator, or the reference may be biased in any way with no effect on the other sections of the LM613, except when a substrate diode conducts, see Electrical Characteristics (Note 1). For example, one amp input may be outside the common-mode range, another amp may be operating as a comparator, and all other sections may have all terminals floating with no effect on the others. Tying inverting input to output and non-inverting input to V⁻ on unused amps is preferred. Unused comparators should have non-inverting input and output tied to V⁺, and inverting input tied to V⁻. Choosing operating points that cause oscillation, such as driving too large a capacitive load, is best avoided.

Op Amp Output Stage

These op amps, like the LM124 series, have flexible and relatively wide-swing output stages. There are simple rules to optimize output swing, reduce cross-over distortion, and optimize capacitive drive capability:

1. Output Swing: Unloaded, the 42 µA pull-down will bring the output within 300 mV of V⁻ over the military temperature range. If more than 42 µA is required, a resistor from output to V⁻ will help. Swing across any load may be improved slightly if the load can be tied to V⁺, at the cost of poorer sinking open-loop voltage gain.

Application Information (Continued)

2. Cross-Over Distortion: The LM613 has lower cross-over distortion (a 1 V_{BE} deadband versus 3 V_{BE} for the LM124), and increased slew rate as shown in the characteristic curves. A resistor pull-up or pull-down will force class-A operation with only the PNP or NPN output transistor conducting, eliminating cross-over distortion.

3. Capacitive Drive: Limited by the output pole caused by the output resistance driving capacitive loads, a pull-down resistor conducting 1 mA or more reduces the output stage NPN r_e until the output resistance is that of the current limit 25Ω. 200 pF may then be driven without oscillation.

Comparator Output Stage

The comparators, like the LM139 series, have open-collector output stages. A pull-up resistor must be added from each output pin to a positive voltage for the output transistor to switch properly. When the output transistor is OFF, the output voltage will be this external positive voltage.

For the output voltage to be under the TTL-low voltage threshold when the output transistor is ON, the output current must be less than 8 mA (over temperature). This impacts the minimum value of pull-up resistor.

The offset voltage may increase when the output voltage is low and the output current is less than 30 μA. Thus, for best accuracy, the pull-up resistor value should be low enough to allow the output transistor to sink more than 30 μA.

Op Amp and Comparator Input Stage

The lateral PNP input transistors, unlike those of most op amps, have BV_{EBO} equal to the absolute maximum supply voltage. Also, they have no diode clamps to the positive supply nor across the inputs. These features make the inputs look like high impedances to input sources producing large differential and common-mode voltages.

Typical Applications
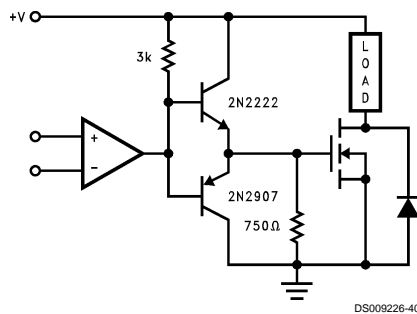
DS009226-40

FIGURE 12. High Current, High Voltage Switch
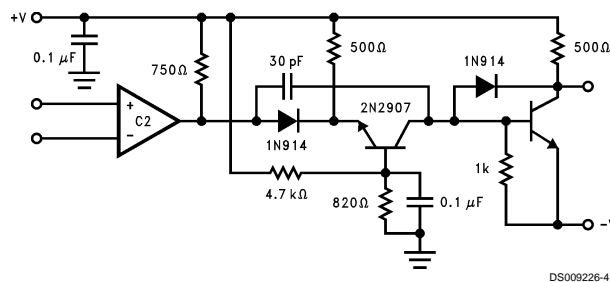
DS009226-41

FIGURE 13. High Speed Level Shifter. Response time is approximately 1.5 μs, where output is either approximately +V or −V.

Typical Applications (Continued)
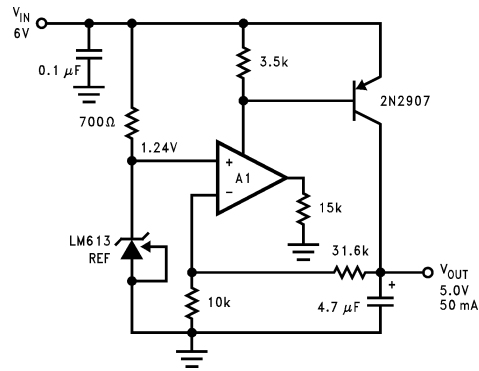
DS009226-42

FIGURE 14. Low Voltage Regulator. Dropout voltage is approximately 0.2V.
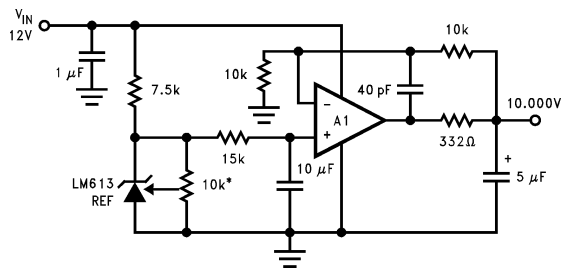
DS009226-43

*10k must be low
t.c. trimpot

FIGURE 15. Ultra Low Noise, 10.00V Reference. Total output noise is typically 14 µV$_{RMS}$.

Typical Applications (Continued)
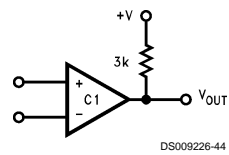
FIGURE 16. Basic Comparator
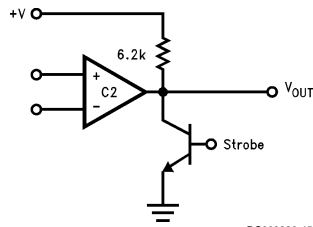
FIGURE 17. Basic Comparator with External Strobe
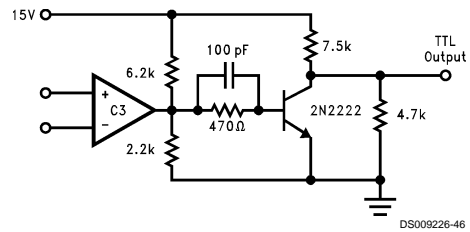
FIGURE 18. Wide-Input Range
Comparator with TTL Output

FIGURE 19. Comparator with
Hysteresis ($\Delta V_H = {}^+V(1k/1M)$)

Physical Dimensions inches (millimeters) unless otherwise noted

$\frac{0.350 \pm 0.008}{(8.890 \pm 0.203)}$

$\frac{0.063 - 0.075}{(1.600 - 1.905)}$

DETAIL A

Top View

Side View

$\frac{0.200 \pm 0.005}{(5.080 \pm 0.127)}$ TYP

$45° \times \frac{0.015 \pm 0.010}{(0.381 \pm 0.254)}$

$\frac{0.015}{(0.381)}$ MIN TYP

$\frac{0.007 - 0.011}{(0.178 - 0.279)}$ R TYP

$\frac{0.022 - 0.028}{(0.559 - 0.711)}$ TYP

$\frac{0.077 - 0.093}{(1.959 - 2.362)}$

PIN #1 INDEX

$\frac{0.045 - 0.055}{(1.143 - 1.397)}$ TYP

$\frac{0.067 - 0.083}{(1.702 - 2.108)}$ TYP

$\frac{0.045 - 0.055}{(1.143 - 1.397)}$

$45° \times \frac{0.040 \pm 0.010}{(1.016 \pm 0.254)}$ 3 PLCS

Bottom View

$\frac{0.003}{(0.076)}$ MIN TYP

$\frac{0.015}{(0.381)}$ MAX TYP

$\frac{0.022}{(0.559)}$ MAX TYP

$\frac{0.006}{(0.152)}$ MIN TYP

Detail A
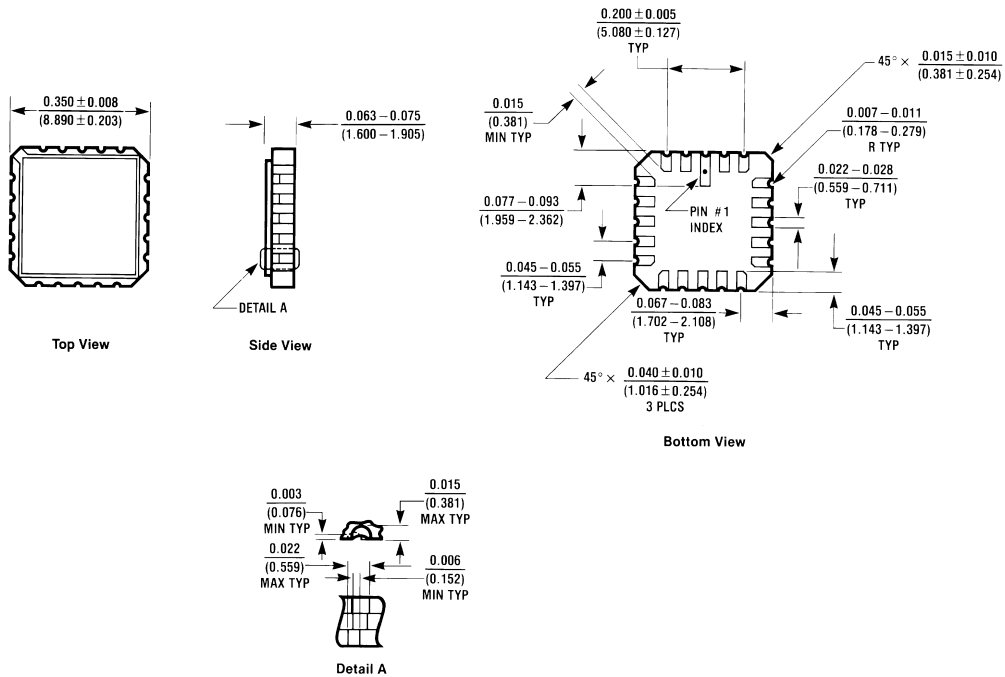
E20A (REV D)

20-Lead Small Outline Package (E)
Order Number LM613AME/883
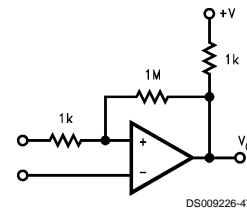**NS Package Number E20A**

$\frac{0.785}{[19.94]}$ MAX

16   9

$0.220 - 0.310$ [5.59 - 7.87]

R $\frac{0.025}{[0.64]}$

1   8

R $\frac{0.005 - 0.020}{[0.13 - 0.51]}$ TYP

$\frac{0.037 \pm 0.005}{[0.94 \pm 0.13]}$ TYP

$\frac{0.005}{[0.13]}$ MIN TYP

$\frac{0.055 \pm 0.005}{[1.40 \pm 0.13]}$ TYP

$\frac{0.020 - 0.060}{[0.51 - 1.52]}$ TYP

$\frac{0.290 - 0.320}{[7.37 - 8.13]}$

GLASS SEALANT

$\frac{0.200}{[5.08]}$ MAX TYP

$\frac{0.180}{[4.57]}$ MAX

$\frac{0.010 \pm 0.002}{[0.25 \pm 0.05]}$ TYP

$\frac{0.150}{[3.81]}$ MIN TYP

$\frac{0.125 - 0.200}{[3.18 - 5.08]}$ TYP

$90° \pm 4°$ TYP

$95° \pm 5°$ TYP

$\frac{0.080}{[2.03]}$ MAX BOTH ENDS

$\frac{0.018 \pm 0.003}{[0.46 \pm 0.08]}$ TYP

$\frac{0.310 - 0.410}{[7.87 - 10.41]}$

J16A (REV L)

$\frac{0.100 \pm 0.010}{[2.54 \pm 0.25]}$ TYP
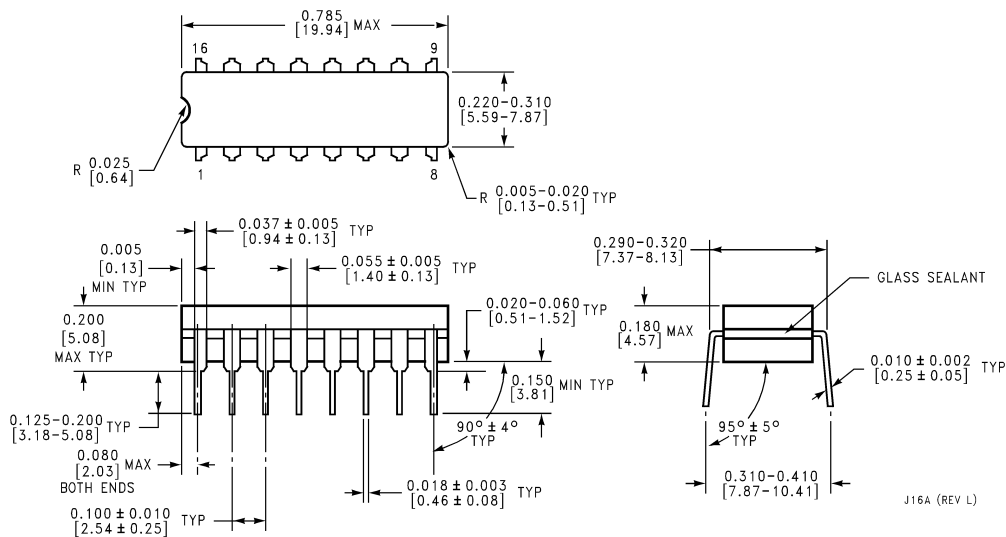
16-Lead Ceramic Dual-In-Line Package (J)
Order Number LM613AMJ/883
NS Package Number J16A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

-B-

0.3977–0.4133
10.10–10.50

16 15 14 13 12 11 10 9

LEAD NO 1
IDENTIFICATION

0.2914–0.2992
7.4–7.6
-C-

0.3940–0.4190
10.00–10.65

1 2 3 4 5 6 7 8

0.050
1.27

0.0138–0.0200
0.350–0.508 TYP

⊕ | 0.010
0.25 Ⓜ | A | C Ⓢ | B

0.0926–0.1043
2.35–2.65

0.0040–0.0118
0.1–0.3

45° X 0.010–0.029
0.25–0.75

0.0091–0.0125
0.23–0.32 TYP ALL LEADS

SEATING
PLANE

0.014
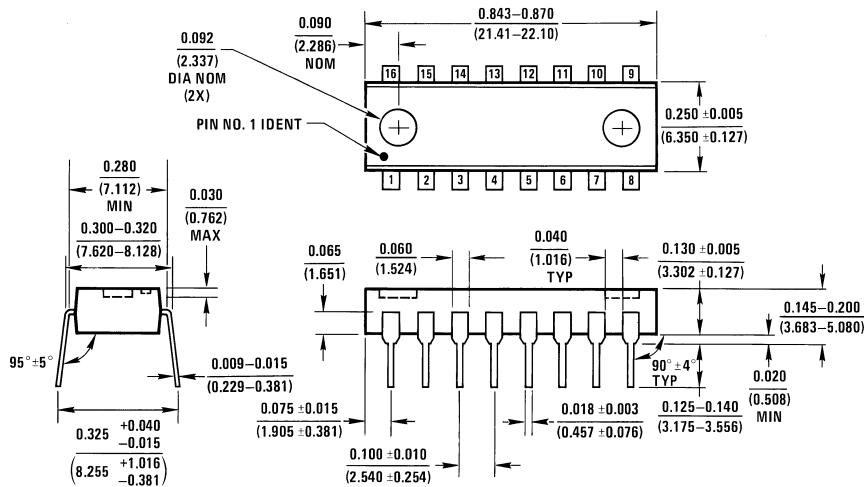0.35

-A-

△ | 0.004
0.1
ALL LEAD TIPS

B MAX TYP
ALL LEADS

0.0160–0.0500
0.40–1.27 TYP ALL LEADS

M16B (REV F)
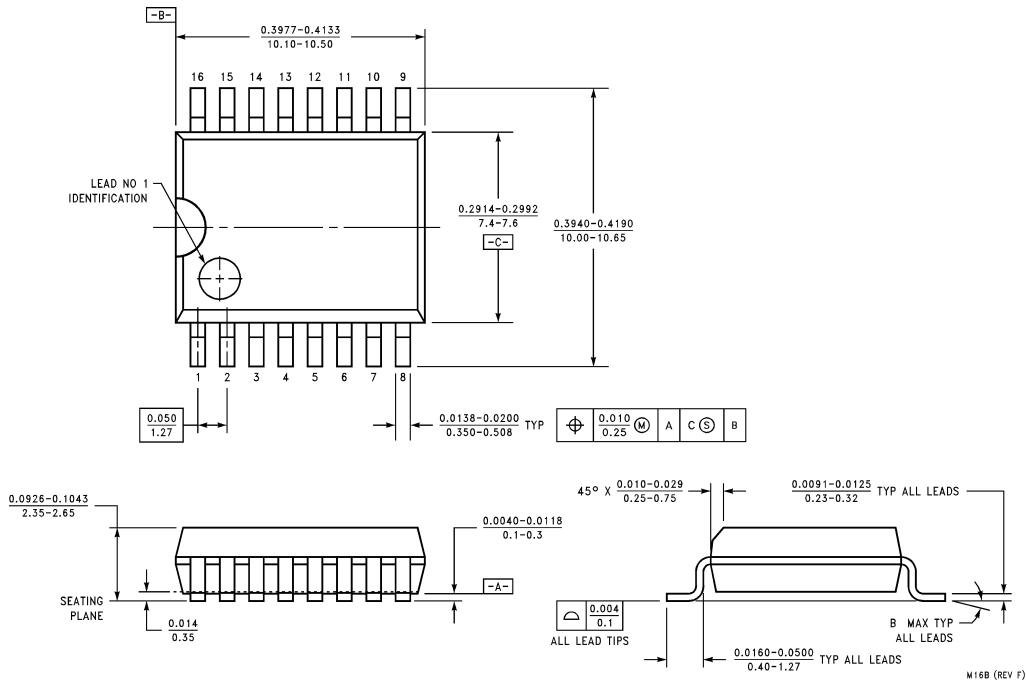
16-Lead Small Outline Package (WM)
Order Number LM613IWM
NS Package Number M16B

0.092
(2.337)
DIA NOM
(2X)

0.090
(2.286)
NOM

0.843–0.870
(21.41–22.10)

16 15 14 13 12 11 10 9

PIN NO. 1 IDENT

0.250 ±0.005
(6.350 ±0.127)

1 2 3 4 5 6 7 8

0.280
(7.112)
MIN

0.030
(0.762)
MAX

0.300–0.320
(7.620–8.128)

0.065
(1.651)

0.060
(1.524)

0.040
(1.016)
TYP

0.130 ±0.005
(3.302 ±0.127)

0.145–0.200
(3.683–5.080)

95° ±5°

0.009–0.015
(0.229–0.381)

90° ±4°
TYP

0.020
(0.508)
MIN

0.075 ±0.015
(1.905 ±0.381)

0.018 ±0.003
(0.457 ±0.076)

0.125–0.140
(3.175–3.556)

0.325 +0.040
−0.015

(8.255 +1.016
−0.381)

0.100 ±0.010
(2.540 ±0.254)

N16A (REV E)

16-Lead Molded Dual-In-Line Package (N)
Order Number LM613CN, LM613AIN, LM613IN, LM613AMN or LM613MN
NS Package Number N16A

Notes

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.